| L Numbe  | r Hits | Search Text  | DB                             | Time stamp       |
|----------|--------|--|--------------------------------|------------------|
| 1        |        | (("6007675") or ("5672239")).PN.   | USPAT;                         | 2002/05/28 11:32 |
| -        | 378708 | h011021/\$.ipc. c23c016/\$.ipc.  | EPO; JPO<br>USPAT;<br>EPO; JPO | 2002/05/23 16:30 |
| -        | 2107   |  | USPAT;                         | 2002/05/23 16:03 |
| -        | 1084   | (etch\$) and (strip\$3) and (clean\$3) (h011021/\$.ipc. c23c016/\$.ipc.) and (etch\$) and (strip\$3) and (clean\$3) and  | EPO; JPO<br>USPAT;<br>EPO; JPO | 2002/05/23 16:32 |
| _        | 255    | (dry\$3)   | USPAT;                         | 2002/05/23 16:34 |
|          |        | <pre>(etch\$) and (strip\$3) and (clean\$3) and (dry\$3)) and ((mov\$3 load\$3 unload\$3 transfer\$3 lift\$3) with (substrate work workpiece object))</pre>  | EPO; JPO                       |                  |
| -        | 37     | <pre>(((h011021/\$.ipc. c23c016/\$.ipc.) and (etch\$) and (strip\$3) and (clean\$3) and (dry\$3)) and ((mov\$3 load\$3 unload\$3 transfer\$3 lift\$3) with (substrate work workpiece object))) and (LCD ("liquid crystal display"))</pre>  | USPAT;<br>EPO; JPO             | 2002/05/23 16:37 |
| -        | 152127 | ,  | USPAT;<br>EPO; JPO             | 2002/05/23 16:31 |
| -        | 961    | (438/\$.ccls. 134/\$.ccls. 156/345.\$.ccls.) and ((etch\$) and (strip\$3) and (clean\$3) and (dry\$3) same (substrate work workpiece wafer))   | USPAT;<br>EPO; JPO             | 2002/05/23 16:33 |
| -        | 403    |  | USPAT;<br>EPO; JPO             | 2002/05/23 16:37 |
| -        | 40     | (((438/\$.ccls. 134/\$.ccls. 156/345.\$.ccls.) and ((etch\$) and (strip\$3) and (clean\$3) and (dry\$3) same (substrate work workpiece wafer))) and ((mov\$3 load\$3 unload\$3 transfer\$3 lift\$3) with (substrate work workpiece wafer))) and (LCD ("liquid")  | USPAT;<br>EPO; JPO             | 2002/05/23 16:49 |
| -        | 363    | crystal display")) (((438/\$.ccls. 134/\$.ccls. 156/345.\$.ccls. ) and ((etch\$) and (strip\$3) and (clean\$3) and (dry\$3) same (substrate work workpiece wafer))) and ((mov\$3 load\$3 unload\$3 transfer\$3 lift\$3) with (substrate work workpiece wafer))) not ((((438/\$.ccls. 134/\$.ccls. 156/345.\$.ccls.) and ((etch\$) and (strip\$3) and (clean\$3) and (dry\$3) same (substrate work workpiece wafer))) and ((mov\$3 load\$3 unload\$3 transfer\$3 lift\$3) with (substrate work workpiece wafer))) and (LCD ("liquid crystal display"))) | USPAT;<br>EPO; JPO             | 2002/05/23 17:01 |
| -        | 55     |  | USPAT;<br>EPO; JPO             | 2002/05/23 17:03 |
| -        | 66     | 156/345.1.ccls.  | USPAT;<br>EPO; JPO             | 2002/05/24 08:49 |
| -        | 35     | 156/345.2.ccls. not 156/345.1.ccls.  | USPAT;<br>EPO; JPO             | 2002/05/24 08:50 |
| - /      | 35     | 156/345.2.ccls.  | USPAT;<br>EPO; JPO             | 2002/05/24 09:45 |
| SylVia - | 37511  | (etch\$3 and strip\$4) and (semiconductor substrate)   | USPAT;<br>EPO; JPO             | 2002/05/24 15:13 |
| ]_ 7~    | 2473   |  | USPAT;<br>EPO; JPO             | 2002/05/24 09:55 |
| -        | 2430   |  | USPAT                          | 2002/05/24 09:52 |

| -   | 1524 | (((etch\$3 and strip\$4) and (semiconductor                                  | USPAT      | 2002/05/24 09:58   |
|-----|------|--|------------|--------------------|
|     |      | substrate)) and (156/345.\$.ccls.  |            |                    |
|     |      | 451/\$.ccls. 216/\$.ccls.)) and (wash\$3                                     |            | 1                  |
|     |      | rins\$3 clean\$3 dip\$3)   |            |                    |
| -   | 876  | ((((etch\$3 and strip\$4) and (semiconductor                                 | USPAT      | 2002/05/24 14:38   |
|     |      | substrate)) and (156/345.\$.ccls.  |            |                    |
|     |      | 451/\$.ccls. 216/\$.ccls.)) and (wash\$3                                     |            |                    |
|     |      | rins\$3 clean\$3 dip\$3)) and (elevator                                      |            |                    |
|     |      | vertical convey\$3 transfer\$3)  |            |                    |
| -   | 310  | ((etch\$3 and strip\$4) and (semiconductor                                   | USPAT      | 2002/05/24 11:01   |
|     |      | substrate)) and (156/345.\$.ccls.)   |            |                    |
| -   | 194  | (((etch\$3 and strip\$4) and (semiconductor                                  | USPAT      | 2002/05/24 11:02   |
|     |      | substrate)) and (156/345.\$.ccls.)) and                                      |            |                    |
|     | _    | (wash\$3 rins\$3 clean\$3 dip\$3)  |            |                    |
| -   | 3    | ("5135608"   "5171393"   "5376212").PN.                                      | USPAT      | 2002/05/24 10:29   |
| -   | 5    | 5672239.URPN.  | USPAT      | 2002/05/24 10:31   |
| -   | 2103 | ((etch\$3 and strip\$4) and (semiconductor                                   | USPAT      | 2002/05/24 11:01   |
|     |      | substrate)) and (216/\$.ccls.)   |            | 0000/05/04 11:00   |
| -   | 1312 | (((etch\$3 and strip\$4) and (semiconductor                                  | USPAT      | 2002/05/24 11:02   |
|     |      | substrate)) and (216/\$.ccls.)) and (wash\$3                                 |            |                    |
|     | 300  | rins\$3 clean\$3 dip\$3)   | IICDAM     | 2002/05/24 11:02   |
| -   | 726  |  | USPAT      | 2002/05/24 11:03   |
|     |      | substrate)) and (216/\$.ccls.)) and (wash\$3                                 |            |                    |
|     |      | rins\$3 clean\$3 dip\$3)) and (elevator                                      |            |                    |
|     | 412  | vertical convey\$3 transfer\$3) ((((etch\$3 and strip\$4) and (semiconductor | USPAT      | 2002/05/24 11:15   |
| -   | 412  | substrate)) and (216/\$.ccls.)) and (wash\$3                                 | USFAI      | 2002/03/24 11:13   |
|     |      | rins\$3 clean\$3 dip\$3)) and (elevator                                      |            |                    |
|     |      | vertical)  |            |                    |
| _   | 374  | (((((etch\$3 and strip\$4) and   | USPAT      | 2002/05/24 14:29   |
| -   | 3/4  | (semiconductor substrate)) and   | 001711     | 2002,03,21 11123   |
|     |      | (216/\$.ccls.)) and (wash\$3 rins\$3 clean\$3                                |            |                    |
|     |      | dip\$3)) and (elevator vertical)) not  |            |                    |
|     |      | ((((etch\$3 and strip\$4) and (semiconductor                                 |            |                    |
|     |      | substrate)) and (156/345.\$.ccls.)) and                                      |            |                    |
|     |      | (wash\$3 rins\$3 clean\$3 dip\$3))   |            |                    |
| _   | 2    | 6074946.URPN.  | USPAT      | 2002/05/24 11:58   |
| _   | 1    | "5369053".PN.  | USPAT      | 2002/05/24 11:59   |
|     | 1    | ((etch\$3 and strip\$4) and (semiconductor                                   | USPAT      | 2002/05/24 14:23   |
|     |      | substrate)) and (451/\$.ccls.) and elevator                                  |            |                    |
| -   | 154  | ((etch\$3 and strip\$4) and (semiconductor                                   | USPAT      | 2002/05/24 14:29   |
|     |      | substrate)) and (451/\$.ccls.)   |            |                    |
| -   | 147  | (((etch\$3 and strip\$4) and (semiconductor                                  | USPAT      | 2002/05/24 14:30   |
|     |      | substrate)) and (451/\$.ccls.)) not  |            |                    |
|     |      | ((((etch\$3 and strip\$4) and  |            | 1                  |
|     |      | (semiconductor substrate)) and   |            |                    |
|     |      | (216/\$.ccls.)) and (wash\$3 rins\$3 clean\$3                                | İ          |                    |
| ]   |      | dip\$3)) and (elevator vertical)) not  |            |                    |
|     |      | ((((etch\$3 and strip\$4) and (semiconductor                                 | [          |                    |
|     |      | substrate)) and (156/345.\$.ccls.)) and                                      |            |                    |
|     | :    | (wash\$3 rins\$3 clean\$3 dip\$3))   |            | 0000 /05 /04 14 00 |
| -   | 5849 | '  | EPO; JPO;  | 2002/05/24 14:39   |
|     | 222  | substrate)   | DERWENT    | 2002/05/24 14:42   |
| -   | 2232 | · · · · · · · · · · · · · · · · · · ·  | EPO; JPO;  | 2002/05/24 14:42   |
|     |      | substrate)) and (h011021/\$.ipc.   | DERWENT    |                    |
| ]_  | 10   | c23c016/\$.ipc.) ((etch\$3 and strip\$4) and (semiconductor                  | EPO; JPO;  | 2002/05/24 14:44   |
| 1 - | 18   | substrate)) and (h011021/\$.ipc. and   | DERWENT    | 2002/03/24 14:44   |
|     |      | c23c016/\$.ipc.)   | DELMENT    |                    |
| 1_  | 192  |  | EPO; JPO;  | 2002/05/24 14:46   |
| -   | 192  | substrate)) and (h011021/\$.ipc.   | DERWENT    | 2002/03/24 14.40   |
|     |      | c23c016/\$.ipc.)) and (wash\$3 rins\$3                                       |            |                    |
|     |      | clean\$3 dip\$3)   | !          |                    |
| _   | ς.   | (etch\$3 and strip\$4) and (semiconductor                                    | USPAT;     | 2002/05/24 15:16   |
|     |      | substrate) and (strip\$4 with elevator)                                      | EPO; JPO   | -332, 33, 21 13.10 |
| _   | 133  |  | USPAT;     | 2002/05/24 15:27   |
|     | 155  | substrate) and elevator  | EPO; JPO   | -552, 55, 2. 20.2. |
|     | l    | Januara Grander  | , 220, 010 |                    |